# NSN 5962-01-430-2308

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## **Body Length:**

Between 0.816 inches and 0.838 inches

## Body Width:

Between 0.430 inches and 0.445 inches

## **Body Height:**

Between 0.088 inches and 0.120 inches

## **Maximum Power Dissipation Rating:**

1.0 watts

#### **Operating Tempurature Range:**

-55.0/+125.0 degrees celsius

#### Storage Tempurature Range:

-65.0/+150.0 degrees celsius

#### **End Application:**

5895-01-412-4427

#### Features Provided:

Monolithic and electrostatic sensitive and low power and burn in, mil-std-883, class b

#### **Inclosure Material:**

Ceramic and glass

## Inclosure Configuration:

Dual-in-line

## **Output Logic Form:**

Complementary-metal oxide-semiconductor logic

## **Terminal Surface Treatment:**

Solder

### **Product Name:**

Microcircuit, memory, digital, cmos, 128k x 8 static random access memory (sram) low power

#### Voltage Rating And Type Per Characteristic:

-0.5 volts input and 7.0 volts input

#### **Time Rating Per Chacteristic:**

35.00 nanoseconds input to output access

#### Memory Device Type:

Ram

## Test Data Document:

96906-mil-std-883 standard (includes industry or association standards, individual manufactureer standards, etc.).

## Terminal Type And Quantity:

32 j-hook

# Shelf Life:

N/a

## Unit Of Measure:

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## Demilitarization:

No

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